Docket No. 740756-2183



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Shunpei YAMAZAKI
)
Serial No. 09/620,968
) Examiner: Nathan W. Ha
Filed: July 20, 2000
) Group Art Unit: 2814
For: METHOD OF FORMING INSULATION FILMS,
CAPACITANCES, AND SEMICONDUCTOR DEVICES
)

Certificate of Mailing

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage for First Class Mail in an envelope addressed to: Commissioner for Patents, P. O. Box 1450, Alexandria, VA 22312/1450, on October 1.7, 2003.

Name: Bonnie I. Garilli

REQUEST FOR ACKNOWLEDGMENT OF INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents Alexandria, VA 22313-1450

Sir:

An Information Disclosure Statement with Form PTO-1449 was filed in the above-identified patent application on July 20, 2000. Applicants have not yet received back from the Examiner a copy of the Form PTO-1449 initialed to acknowledge the fact that the Examiner has considered the cited disclosed information.

The Examiner is requested to initial and return to the undersigned a copy of the subject Form PTO-1449.

Should there be any questions concerning this communication, please telephone the undersigned at the number set forth below.

Respectfully submitted,

Jerome W. Massie IV Registration No. 48,118

Nixon Peabody LLP 401 9th Street, N.W. Suite 900 Washington, DC 20004-2128 (202) 585-8000 (202) 585-8080 FAX

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Form PTO-1 (Rev. 8-83)	449	U.S. Department of Patent and Trade		Attorney Docket No. 0756-2	183	Serial No. Not	Yet Assi	gned	
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Examiner Page	S. S	U.S.	PATENT	DOCUMENTS					
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	3,60	7,679	9/1971	Melroy et al.					
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Attorney Docket No. 0756-2183

Applicant: Shunpei YAMAZAKI

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Form PTO-1449 U.S. Department of Commerce Attorney Docket No. 0756-2183 Serial No. Not Yet Assigned (Rev. 8-83) Patent and Trademark Office Applicant: Shunpei YAMAZAKI INFORMATION DISCLOSURE STATEMENT DCT 2 0 2003 Group: 2811 Filing Date: July 20, 2000 (Use several sheets if necessary) **U.S. PATENT DOCUMENTS** Date Name Class Subclass Filing Date (if Examiner **Document Number** Initial appropriate) 5,047,359 09/10/91 Nagatomo **Pfiester** 5,047,812 10/10/91 10/01/91 Kojima 5,053,842 10/08/91 Huang 5,056,010 Kimura 02/04/92 5,086,010 2/23/93 Suguro 5,189,503 08/04/92 5,136,534 McDavid et al. **FOREIGN PATENT DOCUMENTS** Date Country Class Subclass Translation_ **Document Number** Yes No Full 08/19/81 **United Kingdom** 2 103 879A Full WO 89/02655 03/23/89 PCT **Abstract** JP 01-171275 7/6/89 Japan Abstract 1/31/87 JP 62-23117 Japan Abstract JP 62-298119 12/25/87 Japan Abstract 2/16/90 JP 02-47256 Japan **Abstract** 24/1/91 Japan JP 03-16129 Abstract JP 03-79028 4/4/91 Japan Full EP 445535 11/9/91 European Full 03/01/90 European EP 349187 X 8/16/89 1-203666 Japan Х 11/21/87 62-269363 Japan X 8/17/88 63-199456 Japan Χ 10/4/89 1-248557 Japan Х 3/20/90 2-79475 Japan **Date Considered** Examiner *EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Sheet <u>5</u> of <u>5</u> Serial No. Not Yet Attorney Docket No. 0756-2183 U.S. Department of Commerce Form PTO-1449 Assigned Patent and Trademark Office (Rey_8-83) INFORMATION DISCLOSURE STATEMENT Applicant: Shunpei YAMAZAKI 2 0 2003 (Use several sheets if necessary) Group: 2811 Filing Date: July 20, 2000 TRADEMARY OF FOREIGN PATENT DOCUMENTS Subclass Translation Class Country Date **Document Number** Yes No Abstract 6/8/84 Japan JP 59-99726 Abstract 03/28/89 Japan JP 64-82557 Abstract 09/08/89 Japan JP 01-225148 **Abstract** 02/27/92 Japan JP 04-61337 **Abstract** 01/12/85 Japan 60-005555

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